

## SPECIFICATIONS

- ▶ Chemical formula:  $\text{Al}_2\text{O}_3$
- ▶ Chemical name: Sapphire
- ▶ Appearance: Dense sintered sapphire
- ▶ Main characteristics: Single crystal, high heat resistance, high chemical resistance
- ▶ Main applications: Thin film substrates, windows, chemically resistant parts
- ▶ Colour: Transparent

## MECHANICAL & PHYSICAL CHARACTERISTICS (TYP.)

<b>Density</b>		[g/cm <sup>3</sup> ]	JIS R 1634	3.97	
<b>Water absorption</b>		[%]	JIS C 2141	0	
<b>Vickers hardness HV9.807N</b>		[GPa]	JIS R 1610	Surface a	22.5
<b>Flexural strength 3 P.B.</b>		[MPa]	JIS R 1601	Surface a Axis c	690
<b>Compressive strength</b>		[MPa]	JIS R 1608	2,940	
<b>Young's modulus of elasticity</b>		[GPa]	JIS R 1602	470	
<b>Poisson's ratio</b>		[-]	JIS R 1602	-	
<b>Fracture toughness (SEPB)</b>		[MPa*m <sup>0.5</sup> ]	JIS R 1607	-	
<b>Coefficient of linear thermal expansion</b>	40 - 400 °C	[*10 <sup>-6</sup> /K]	JIS R 1618	Parallel to Axis c	7.7
	40 - 800 °C			Vertical to Axis c	7.0
<b>Thermal conductivity</b>		[W/(m*K)]	JIS R 1611	41	
<b>Specific heat capacity</b>		[J/(g*K)]	JIS R 1611	0.75	
<b>Thermal shock temperature difference</b>		[°C]	JIS R 1648	-	
<b>Dielectric strength</b>		[kV/mm]	JIS C 2141	48	
<b>Volume resistivity</b>	20 °C	[Ω*cm]	JIS C 2141	>10 <sup>14</sup>	
	300 °C			-	
	500 °C			10 <sup>10</sup>	
<b>Dielectric constant</b>		-	JIS C 2141	Parallel to Axis c	11.5
				Vertical to Axis c	9.3
<b>Dielectric loss angle</b>		[*10 <sup>-4</sup> ]	JIS C 2141	<1	
<b>Loss factor</b>		[*10 <sup>-4</sup> ]	JIS C 2141	-	

The values are typical material properties and may vary according to products configuration and manufacturing process. For more details, please feel free to contact us.